#### System Integration of Superconducting Tunnel Junction Detectors for Measurement of Unrevealed Material Information



## **System integration**





#### **Superconducting detectors**

	Two spectroscopic domains		
Туре	Energy	Time (decay)	Temp.
Calorimeter TES, MMC	Extremely high (1.2 eV@ 6 keV)	Slow (ms)	< 0.1 K
STJ	High (4.1 eV@ 392 V)	Fast (µs)	0.3 K
SSPD (nano-strip)	N/A	Extremely fast (1 ns)	> 4.2 K

Third demand for superconductivity has emerged: high spatial resolution SSPD for synchrotron radiation facilities.

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### X-ray Absorption Near Edge Structure (XANES) and X-ray Emission Spectroscopy (XES)



## High energy resolution is required for element selection and line shape







100-200 µm



### **STJ detector**



 $\epsilon = 1.7\Delta = 2.6 \text{ meV} (\sim 1 \text{ eV in Si})$ Debye energy( $\Sigma_D$ ) = 24 meV (Nb) The  $\epsilon$  value, which is a threshold energy to create quasiparticles, is1.7 $\Delta$ , M. Kurakado, NIM (1969).

$$\frac{\Delta E}{E} \propto \frac{\sigma_N}{\langle N \rangle},$$
  
$$\Delta E_{\rm FWHM} = 2.355 \sqrt{F \varepsilon E} = \sim 2 \text{eV}@6 \text{ keV}$$
  
$$0.5 \text{ eV}@400 \text{ eV} (\text{N-}K \text{ line})$$

Photon counting rate = > 1000 cps/pixel

# Real energy resolution @ synchrotron radiation



### Energy resolution vs. photon energy of the best pixel



## High count rate of the 100-ch STJ system



#### **Fluorescence Yield-XAFS**



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#### XAFS of N dopant in SiC (4 x 10<sup>19</sup> cm<sup>-3</sup>) **XANES** experiment **First-principles calculation** а а 3C 1800 °C Absorption [a.u.] Si site Absorption [a.u.] 1400 °C C site SiC:N 4H as-implanted Si sites 380 400 420 440 460 C sites Photon energy [eV] 380 400 420 440 460 Photon energy [eV] b lon channeling b Substitution sites Disorder [ 10<sup>21</sup> atoms/cm<sup>3</sup> ] as-implanted 3 2 3C-Si C 1800 °C 3C-C 4H-Si 200 300 400 100 0 Depth [nm]

M. Ohkubo, et al., Sci. Rep. 2, 831 (2012); DOI:10.1038/srep00831.

## X-ray emission spectroscopy of C-K



#### Latest STJ array detector for XAFS and PIXE



## Upgrade to 512-1024 pixels



筑波大学 University of Tsukuba



CRAVITY

G. Fujii and M. Ukibe 1024 pixels



6 MeV Van de Graff accelerator

#### S. Shiki

Microbeam Particle-Induced X-ray Emission (PIXE) with 512 STJs

# Summary

- SR: X-ray absorption spectroscopy (XAS) for light elements
- SEM: X-ray emission spectroscopy for light elements
- Ion accelerator: Particle induced X-ray emission (PIXE)
- Astrophysics: neutrino mass determination by far-IR photon spectroscopy (15 - 30 meV range) with Tsukuba Uni.
- Atmospheric escape from planets (FLUXONICS)
- Prebiotic organic molecule in universe (FLUXONICS)
- New trend of SSPD: high spatial resolution (5 meV)



